

## SHORT BIO

**Marko Radosavljević** is a Full Professor in the Department of Electrical Engineering at the University of Notre Dame, which he joined in January of 2026. He received PhD in physics from University of Pennsylvania in 2001, followed by 2 years as a postdoc at IBM T.J. Watson Research Center in New York. In 2003, he joined the Components Research (CR) division of Intel Corporation in Oregon. Marko's research has been focused on non-Si transistors, such as InP, InSb, GaN material families as well as carbon nanotubes for applications in logic, RF and power delivery. Between 2019 and 2025, he lead a monolithic 3D integration group in CR, enabling new functionalities and providing ultimate transistor density improvements. He is a senior member of IEEE and serves the community as editor of IEEE Transactions of Materials for Electron Devices after serving as editor of EDL and committee member for IEDM conference.